

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







MPPS™ Miniature Package Power Solutions DUAL 15V NPN LOW SATURATION SWITCHING TRANSISTOR

SUMMARY

 V_{CEO} =15V; R_{SAT} = 45m Ω ; I_{C} = 4.5A

DESCRIPTION

Packaged in the innovative 3mm x 2mm MLP (Micro Leaded Package) outline, these new 4th generation low saturation dual transistors offer extremely low on state losses making them ideal for use in DC-DC circuits and various driving and power management functions.

Additionally users gain several other key benefits:

Performance capability equivalent to much larger packages

Improved circuit efficiency & power levels

PCB area and device placement savings

Lower package height (nom. 0.9mm)

Reduced component count

FEATURES

- Low Equivalent On Resistance
- Extremely Low Saturation Voltage (100mV @1A)
- h_{FE} characterised up to 12A
- I_C= 4.5A Continuous Collector Current
- 3mm x 2mm MLP

APPLICATIONS

- DC DC Converters (FET Drivers)
- · Charging circuits
- Power switches
- Motor control

ORDERING INFORMATION

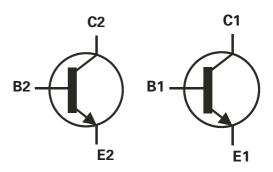
DEVICE	REEL	TAPE WIDTH	QUANTITY PER REEL
ZXTDAM832TA	7′′	8mm	3000
ZXTDAM832TC	13′′	8mm	10000

DEVICE MARKING

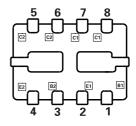
DAA



3mm x 2mm (Dual die) MLP



PINOUT



3mm x 2mm MLP underside view



ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	LIMIT	UNIT
Collector-Base Voltage	V _{CBO}	40	V
Collector-Emitter Voltage	V _{CEO}	15	V
Emitter-Base Voltage	V _{EBO}	7.5	V
Peak Pulse Current	I _{CM}	15	A
Continuous Collector Current (a)(f)	I _C	4.5	A
Continuous Collector Current (b)(f)	I _C	5.0	A
Base Current	IB	1000	mA
Power Dissipation at TA=25°C (a)(f) Linear Derating Factor	P _D	1.5 12	W mW/°C
Power Dissipation at TA=25°C (b)(f) Linear Derating Factor	P _D	2.45 19.6	W mW/°C
Power Dissipation at TA=25°C (c)(f) Linear Derating Factor	P _D	1 8	W mW/°C
Power Dissipation at TA=25°C (d)(f) Linear Derating Factor	P _D	1.13 9	W mW/°C
Power Dissipation at TA=25°C (d)(g) Linear Derating Factor	P _D	1.7 13.6	W mW/°C
Power Dissipation at TA=25°C (e)(g) Linear Derating Factor	P _D	3 24	W mW/°C
Operating and Storage Temperature Range	T _j :T _{stg}	-55 to +150	°C

THERMAL RESISTANCE

THE HIVIAL HEGIOTANOL							
PARAMETER	SYMBOL	VALUE	UNIT				
Junction to Ambient (a)(f)	$R_{\theta JA}$	83.3	°C/W				
Junction to Ambient (b)(f)	$R_{\theta JA}$	51	°C/W				
Junction to Ambient (c)(f)	$R_{\theta JA}$	125	°C/W				
Junction to Ambient (d)(f)	$R_{\theta JA}$	111	°C/W				
Junction to Ambient (d)(g)	$R_{\theta JA}$	73.5	°C/W				
Junction to Ambient (e)(g)	$R_{\theta JA}$	41.7	°C/W				

Notes

(a) For a dual device surface mounted on 8 sq cm single sided 2oz copper on FR4 PCB, in still air conditions with all exposed pads attached. The copper area is split down the centre line into two separate areas with one half connected to each half of the dual device.

(b) Measured at t-5 secs for a dual device surface mounted on 8 sq cm single sided 2oz copper on FR4 PCB, in still air conditions with all exposed pads attached. The copper area is split down the centre line into two separate areas with one half connected to each half of the dual device.

(c) For a dual device surface mounted on 8 sq cm single sided 2oz copper on FR4 PCB, in still air conditions with minimal lead connections only.

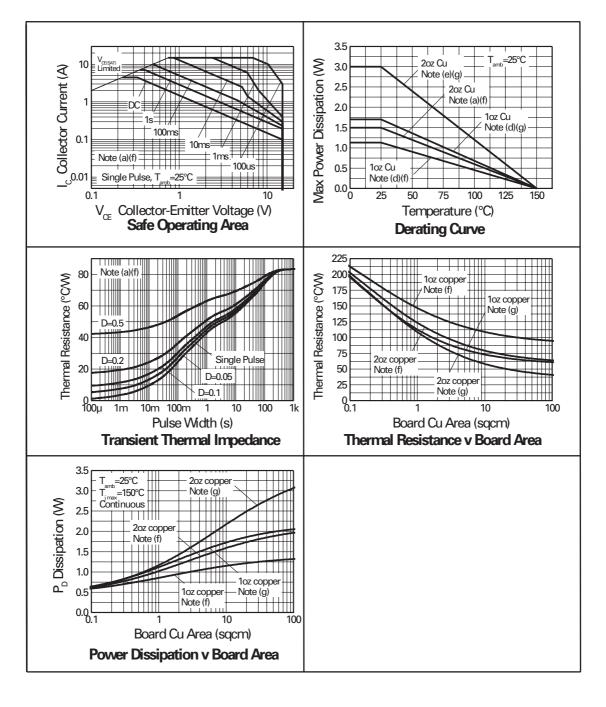
(d) For a dual device surface mounted on 10 sq cm single sided 1oz copper on FR4 PCB, in still air conditions with all exposed pads attached attached. The copper area is split down the centre line into two separate areas with one half connected to each half of the dual device.

(e) For a dual device surface mounted on 85 sq cm single sided 2oz copper on FR4 PCB, in still air conditions with all exposed pads attached attached. The copper area is split down the centre line into two separate areas with one half connected to each half of the dual device.

- (f) For a dual device with one active die.
- (g) For dual device with 2 active die running at equal power.
- (h) Repetitive rating pulse width limited by max junction temperature. Refer to Transient Thermal Impedance graph.
- (i) The minimum copper dimensions required for mounting are no smaller than the exposed metal pads on the base of the device as shown in the package dimensions data. The thermal resistance for a dual device mounted on 1.5mm thick FR4 board using minimum copper 1 oz weight, 1mm wide tracks and one half of the device active is Rth = 250°C/W giving a power rating of Ptot = 500mW.



TYPICAL CHARACTERISTICS





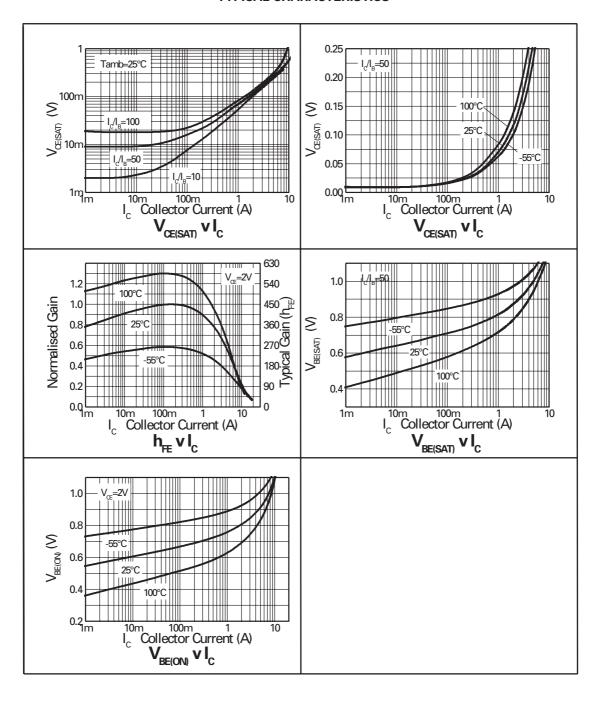
ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}C$ unless otherwise stated).

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS.	
Collector-Base Breakdown Voltage	V _{(BR)CBO}	40	70		V	Ι _C =100μΑ	
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	15	18		V	I _C =10mA*	
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	7.5	8.2		V	I _E =100μA	
Collector Cut-Off Current	I _{CBO}			25	nA	V _{CB} =32V	
Emitter Cut-Off Current	I _{EBO}			25	nA	V _{EB} =6V	
Collector Emitter Cut-Off Current	I _{CES}			25	nA	V _{CES} =12V	
Collector-Emitter Saturation Voltage	V _{CE(sat)}		8 70 165 240 200	14 100 200 280	mV mV mV mV	I _C =0.1A, I _B =10mA* I _C =1A, I _B =10mA* I _C =3A, I _B =50mA* I _C =4.5A, I _B =50mA*	
Base-Emitter Saturation Voltage	V _{BE(sat)}		0.94	1.00	V	I _C =4.5A, I _B =50mA*	
Base-Emitter Turn-On Voltage	V _{BE(on)}		0.88	0.95	V	I _C =4.5A, V _{CE} =2V*	
Static Forward Current Transfer Ratio	h _{FE}	200 300 200 150	415 450 320 240 80			I _C =10mA, V _{CE} =2V* I _C =0.2A, V _{CE} =2V* I _C =3A, V _{CE} =2V* I _C =5A, V _{CE} =2V* I _C =12A, V _{CE} =2V*	
Transition Frequency	f _T	80	120		MHz	I _C =50mA, V _{CE} =10V f=100MHz	
Output Capacitance	C _{obo}		30	40	pF	V _{CB} =10V, f=1MHz	
Turn-On Time	t _(on)		120		ns	V _{CC} =10V, I _C =1A	
Turn-Off Time	t _(off)		160		ns	I _{B1} =I _{B2} =10mA	

^{*}Measured under pulsed conditions. Pulse width=300 μ s. Duty cycle $\leq 2\%$

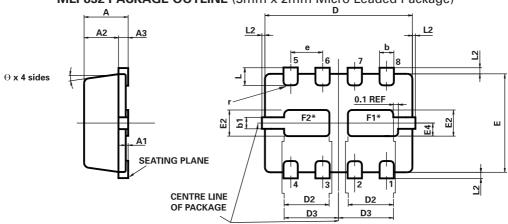


TYPICAL CHARACTERISTICS



ZETEX

MLP832 PACKAGE OUTLINE (3mm x 2mm Micro Leaded Package)



*Exposed Flags. Solder connection to improve thermal dissipation is optional,

F1 at collector 1 potential F2 at collector 2 potential

CONTROLLING DIMENSIONS IN MILLIMETRES APPROX. CONVERTED DIMENSIONS IN INCHES

MLP832 PACKAGE DIMENSIONS

	MILLIN	IETRES	INC	HES		MILLIMETRES		INCHES	
DIM	MIN.	MAX.	MIN.	MAX.	DIM	MIN.	MAX.	MIN.	MAX.
Α	0.80	1.00	0.031	0.039	е	0.65 REF		0.0256 BSC	
A1	0.00	0.05	0.00	0.002	Е	2.00	BSC	0.0787	7 BSC
A2	0.65	0.75	0.0255	0.0295	E2	0.43	0.63	0.017	0.0249
АЗ	0.15	0.25	0.006	0.0098	E4	0.16	0.36	0.006	0.014
b	0.24	0.34	0.009	0.013	L	0.20	0.45	0.0078	0.0157
b1	0.17	0.30	0.0066	0.0118	L2		0.125	0.00	0.005
D	3.00	BSC	0.118	BSC	r	0.075 BSC		0.0029 BSC	
D2	0.82	1.02	0.032	0.040	θ	0°	12°	0°	12°

© Zetex plc 2002

Europe		Americas	Asia Pacific
Zetex plc Fields New Road Chadderton	Zetex GmbH Streitfeldstraße 19 D-81673 München	Zetex Inc 700 Veterans Memorial Hwy Hauppauge, NY11788	Zetex (Asia) Ltd 3701-04 Metroplaza, Tower 1 Hing Fong Road
Oldham, OL9 8NP United Kingdom Telephone (44) 161 622 4422 Fax: (44) 161 622 4420 uksales@zetex.com	Germany Telefon: (49) 89 45 49 49 0 Fax: (49) 89 45 49 49 europe.sales@zetex.com	USA Telephone: (631) 360 2222 Fax: (631) 360 8222 usa.sales@zetex.com	Kwai Fong Hong Kong Telephone: (852) 26100 611 Fax: (852) 24250 494 asia.sales@zetex.com

These offices are supported by agents and distributors in major countries world-wide.

This publication is issued to provide outline information only which (unless agreed by the Company in writing) may not be used, applied or reproduced for any purpose or form part of any order or contract or be regarded as a representation relating to the products or services concerned. The Company reserves the right to alter without notice the specification, design, price or conditions of supply of any product or service.

For the latest product information, log on to $\boldsymbol{www.zetex.com}$

